# Elements of Power Electronics PART I: Bases 

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## Goal and expectations

The goal of the course is to provide a toolbox that allows you to:

- understand power electronics concepts and topologies,
- to model a switching converter,
- to build it (including its magnetic components) and,
- to control it (with digital control).

Power Electronics is a huge area and the correct approach is to focus on understanding concepts.

## Organization and material

The course is divided in three parts:

- PART I: Bases
- PART II: Topologies and applications
- PART III: Digital control

In PART I and PART II, chapters are numbered according to the reference book [1].
In PART III, chapters are numbered according to the reference book [2].

## PART I: Bases

- Chapter 1: Introduction
- Chapter 2: Principles of Steady-State Converter Analysis
- Chapter 3: Steady-State Equivalent Circuit Modeling, Losses, and Efficiency
- Chapter 13: Basic Magnetics Theory
- Chapter 4: Switch Realization
- Chapter 5: The Discontinuous Conduction Mode
- Chapter 19: Resonant Converters


## Chapter 1: Introduction

ELEC0055: Elements of Power Electronics - Fall 2020

# Fundamentals of Power Electronics 

## Second edition

Robert W. Erickson<br>Dragan Maksimovic<br>University of Colorado, Boulder

### 1.1 Introduction to Power Processing



Dc-dc conversion: Change and control voltage magnitude Ac-dc rectification: Possibly control dc voltage, ac current
Dc-ac inversion: Produce sinusoid of controllable magnitude and frequency
Ac-ac cycloconversion: Change and control voltage magnitude and frequency

## Control is invariably required



## High efficiency is essential

$\eta=\frac{P_{\text {out }}}{P_{\text {in }}}$

$$
P_{\text {loss }}=P_{\text {in }}-P_{\text {out }}=P_{\text {out }}\left(\frac{1}{\eta}-1\right)
$$

High efficiency leads to low power loss within converter
Small size and reliable operation is then feasible
Efficiency is a good measure of converter performance


## A high-efficiency converter



A goal of current converter technology is to construct converters of small size and weight, which process substantial power at high efficiency

## Devices available to the circuit designer



## Devices available to the circuit designer



Signal processing: avoid magnetics

## Devices available to the circuit designer



Power processing: avoid lossy elements

## Power loss in an ideal switch

Switch closed: $\quad v(t)=0$

Switch open: $\quad i(t)=0$
In either event: $\quad p(t)=v(t) i(t)=0$

Ideal switch consumes zero power

## A simple dc-dc converter example



Input source: 100V
Output load: 50V, 10A, 500W
How can this converter be realized?

## Dissipative realization

## Resistive voltage divider



## Dissipative realization

Series pass regulator: transistor operates in active region


## Use of a SPDT switch



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## The switch changes the dc voltage level



$$
\begin{aligned}
& D=\text { switch duty cycle } \\
& \quad 0 \leq D \leq 1 \\
& \\
& T_{s}=\text { switching period } \\
& \begin{aligned}
f_{s} & =\text { switching frequency } \\
& =1 / T_{s}
\end{aligned}
\end{aligned}
$$

DC component of $v_{s}(t)=$ average value:

$$
V_{s}=\frac{1}{T_{s}} \int_{0}^{T_{s}} v_{s}(t) d t=D V_{g}
$$

## Addition of low pass filter

Addition of (ideally lossless) $L$-C low-pass filter, for removal of switching harmonics:


- Choose filter cutoff frequency $f_{0}$ much smaller than switching frequency $f_{s}$
- This circuit is known as the "buck converter"


## Addition of control system for regulation of output voltage



## The boost converter



## A single-phase inverter



> "H-bridge"
> Modulate switch duty cycles to obtain sinusoidal low-frequency component

### 1.2 Several applications of power electronics

Power levels encountered in high-efficiency converters

- less than 1 W in battery-operated portable equipment
- tens, hundreds, or thousands of watts in power supplies for computers or office equipment
- kW to MW in variable-speed motor drives
- 1000 MW in rectifiers and inverters for utility dc transmission lines


## Chapter 2: Principles of Steady-State Converter Analysis

- 2.1 Introduction
- 2.2 Inductor volt-second balance, capacitor charge balance, and the small ripple approximation
- 2.3 Boost converter example
- 2.4 Cuk converter example
- 2.5 Estimating the ripple in converters containing twopole low-pass filters
- 2.6 Summary of key points


### 2.1 Introduction Buck converter

SPDT switch changes dc component


Switch output voltage waveform

Duty cycle $D$ :

$$
0 \leq D \leq 1
$$

complement $D^{\prime}$ :
$D^{\prime}=1-D$

## Dc component of switch output voltage



Fourier analysis: Dc component = average value

$$
\begin{aligned}
& \left\langle v_{s}\right\rangle=\frac{1}{T_{s}} \int_{0}^{T_{s}} v_{s}(t) d t \\
& \left\langle v_{s}\right\rangle=\frac{1}{T_{s}}\left(D T_{s} V_{g}\right)=D V_{g}
\end{aligned}
$$

## Insertion of low-pass filter to remove switching harmonics and pass only dc component



$$
v \approx\left\langle v_{s}\right\rangle=D V_{g}
$$

## Three basic dc-dc converters



## Objectives of this chapter

- Develop techniques for easily determining output voltage of an arbitrary converter circuit
- Derive the principles of inductor volt-second balance and capacitor charge (amp-second) balance
- Introduce the key small ripple approximation
- Develop simple methods for selecting filter element values
- Illustrate via examples
2.2. Inductor volt-second balance, capacitor charge balance, and the small ripple approximation

Actual output voltage waveform, buck converter

Buck converter containing practical low-pass filter


Actual output voltage waveform

$$
v(t)=V+v_{\text {riple }}(t)
$$



## The small ripple approximation

$$
v(t)=V+v_{\text {ripple }}(t)
$$



In a well-designed converter, the output voltage ripple is small. Hence, the waveforms can be easily determined by ignoring the ripple:

$$
\begin{gathered}
\left\|v_{\text {ripple }}\right\| \ll V \\
v(t) \approx V
\end{gathered}
$$

## Buck converter analysis: inductor current waveform



## Inductor voltage and current Subinterval 1: switch in position 1

Inductor voltage

$$
v_{L}=V_{g}-v(t)
$$

Small ripple approximation:

$$
v_{L} \approx V_{g}-V
$$



Knowing the inductor voltage, we can now find the inductor current via

$$
v_{L}(t)=L \frac{d i_{L}(t)}{d t}
$$

Solve for the slope:

$$
\frac{d i_{L}(t)}{d t}=\frac{v_{L}(t)}{L} \approx \frac{V_{g}-V}{L}
$$

$\Rightarrow$ The inductor current changes with an essentially constant slope

## Inductor voltage and current Subinterval 2: switch in position 2

Inductor voltage

$$
v_{L}(t)=-v(t)
$$

Small ripple approximation:

$$
v_{L}(t) \approx-V
$$



Knowing the inductor voltage, we can again find the inductor current via

$$
v_{L}(t)=L \frac{d i_{L}(t)}{d t}
$$

Solve for the slope:

$$
\frac{d i_{L}(t)}{d t} \approx-\frac{V}{L}
$$

$\Rightarrow$ The inductor current changes with an essentially constant slope

## Inductor voltage and current waveforms



## Determination of inductor current ripple magnitude

$$
\begin{aligned}
& \left(\text { change in } i_{L}\right)=(\text { slope })(\text { length of subinterval }) \\
& \left(2 \Delta i_{L}\right)=\left(\frac{V_{g}-V}{L}\right)\left(D T_{s}\right) \\
& \Rightarrow \quad \Delta i_{L}=\frac{V_{g}-V}{2 L} D T_{s} \quad L=\frac{V_{g}-V}{2 \Delta i_{L}} D T_{s}
\end{aligned}
$$

## Inductor current waveform during turn-on transient



When the converter operates in equilibrium:

$$
i_{L}\left((n+1) T_{s}\right)=i_{L}\left(n T_{s}\right)
$$

## The principle of inductor volt-second balance: Derivation

Inductor defining relation:

$$
v_{L}(t)=L \frac{d i_{L}(t)}{d t}
$$

Integrate over one complete switching period:

$$
i_{L}\left(T_{s}\right)-i_{L}(0)=\frac{1}{L} \int_{0}^{T_{s}} v_{L}(t) d t
$$

In periodic steady state, the net change in inductor current is zero:

$$
0=\int_{0}^{T_{s}} v_{L}(t) d t
$$

Hence, the total area (or volt-seconds) under the inductor voltage waveform is zero whenever the converter operates in steady state.
An equivalent form:

$$
0=\frac{1}{T_{s}} \int_{0}^{T_{s}} v_{L}(t) d t=\left\langle v_{L}\right\rangle
$$

The average inductor voltage is zero in steady state.

## Inductor volt-second balance: Buck converter example

Inductor voltage waveform, previously derived:


Integral of voltage waveform is area of rectangles:

$$
\lambda=\int_{0}^{T_{s}} v_{L}(t) d t=\left(V_{g}-V\right)\left(D T_{s}\right)+(-V)\left(D^{\prime} T_{s}\right)
$$

Average voltage is

$$
\left\langle v_{L}\right\rangle=\frac{\lambda}{T_{s}}=D\left(V_{g}-V\right)+D^{\prime}(-V)
$$

Equate to zero and solve for $V$ :

$$
0=D V_{g}-\left(D+D^{\prime}\right) V=D V_{g}-V \quad \Rightarrow \quad V=D V_{g}
$$

## The principle of capacitor charge balance: Derivation

Capacitor defining relation:

$$
i_{C}(t)=C \frac{d v_{c}(t)}{d t}
$$

Integrate over one complete switching period:

$$
v_{C}\left(T_{s}\right)-v_{c}(0)=\frac{1}{C} \int_{0}^{T_{s}} i_{c}(t) d t
$$

In periodic steady state, the net change in capacitor voltage is zero:

$$
0=\frac{1}{T_{s}} \int_{0}^{T_{s}} i_{C}(t) d t=\left\langle i_{c}\right\rangle
$$

Hence, the total area (or charge) under the capacitor current waveform is zero whenever the converter operates in steady state. The average capacitor current is then zero.

### 2.3 Boost converter example



## Boost converter analysis



## Subinterval 1: switch in position 1

Inductor voltage and capacitor current

$$
\begin{aligned}
& v_{L}=V_{g} \\
& i_{C}=-v / R
\end{aligned}
$$

Small ripple approximation:

$$
\begin{aligned}
& v_{L}=V_{g} \\
& i_{C}=-V / R
\end{aligned}
$$



## Subinterval 2: switch in position 2

Inductor voltage and capacitor current

$$
\begin{aligned}
v_{L} & =V_{g}-v \\
i_{C} & =i_{L}-v / R
\end{aligned}
$$

Small ripple approximation:

$$
\begin{aligned}
v_{L} & =V_{g}-V \\
i_{C} & =I-V / R
\end{aligned}
$$



## Inductor voltage and capacitor current waveforms



## Inductor volt-second balance

Net volt-seconds applied to inductor over one switching period:

$$
\int_{0}^{T_{s}} v_{L}(t) d t=\left(V_{g}\right) D T_{s}+\left(V_{g}-V\right) D^{\prime} T_{s}
$$



Equate to zero and collect terms:

$$
V_{g}\left(D+D^{\prime}\right)-V D^{\prime}=0
$$

Solve for V :

$$
V=\frac{V_{g}}{D^{\prime}}
$$

The voltage conversion ratio is therefore

$$
M(D)=\frac{V}{V_{g}}=\frac{1}{D^{\prime}}=\frac{1}{1-D}
$$

## Conversion ratio $M(D)$ of the boost converter



## Determination of inductor current dc component

Capacitor charge balance:
$\int_{0}^{T_{s}} i_{C}(t) d t=\left(-\frac{V}{R}\right) D T_{s}+\left(I-\frac{V}{R}\right) D^{\prime} T_{s}$


Collect terms and equate to zero:

$$
-\frac{V}{R}\left(D+D^{\prime}\right)+I D^{\prime}=0
$$

Solve for $I$ :

$$
I=\frac{V}{D^{\prime} R}
$$

Eliminate $V$ to express in terms of $V_{g}$ :

$$
I=\frac{V_{g}}{D^{\prime 2} R}
$$

## Determination of inductor current ripple

Inductor current slope during subinterval 1:

$$
\frac{d i_{L}(t)}{d t}=\frac{v_{L}(t)}{L}=\frac{V_{g}}{L}
$$

Inductor current slope during subinterval 2:


$$
\frac{d i_{L}(t)}{d t}=\frac{v_{L}(t)}{L}=\frac{V_{g}-V}{L}
$$

Change in inductor current during subinterval 1 is (slope) (length of subinterval):

$$
2 \Delta i_{L}=\frac{V_{g}}{L} D T_{s}
$$

Solve for peak ripple:

$$
\Delta i_{L}=\frac{V_{g}}{2 L} D T_{s}
$$

- Choose $L$ such that desired ripple magnitude is obtained


## Determination of capacitor voltage ripple

Capacitor voltage slope during subinterval 1:

$$
\frac{d v_{c}(t)}{d t}=\frac{i_{c}(t)}{C}=\frac{-V}{R C}
$$

Capacitor voltage slope during subinterval 2:


$$
\frac{d v_{C}(t)}{d t}=\frac{i_{C}(t)}{C}=\frac{I}{C}-\frac{V}{R C}
$$

Change in capacitor voltage during subinterval 1 is (slope) (length of subinterval):

$$
-2 \Delta v=\frac{-V}{R C} D T_{s}
$$

Solve for peak ripple:

$$
\Delta v=\frac{V}{2 R C} D T_{s}
$$

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- Choose $C$ such that desired voltage ripple magnitude is obtained
- In practice, capacitor equivalent series resistance (esr) leads to increased voltage ripple


### 2.4 Cuk converter example

Cuk converter, with ideal switch


Cuk converter: practical realization using MOSFET and diode


## Cuk converter circuit with switch in positions 1 and 2

Switch in position 1: MOSFET conducts

Capacitor $C_{1}$ releases energy to output


Switch in position 2: diode conducts

Capacitor $C_{1}$ is charged from input


## Waveforms during subinterval 1 MOSFET conduction interval

Inductor voltages and capacitor currents:

$$
\begin{aligned}
& v_{L 1}=V_{g} \\
& v_{L 2}=-v_{1}-v_{2} \\
& i_{C 1}=i_{2} \\
& i_{C 2}=i_{2}-\frac{v_{2}}{R}
\end{aligned}
$$



Small ripple approximation for subinterval 1:

$$
\begin{aligned}
& v_{L 1}=V_{g} \\
& v_{L 2}=-V_{1}-V_{2} \\
& i_{C 1}=I_{2} \\
& i_{C 2}=I_{2}-\frac{V_{2}}{R}
\end{aligned}
$$

## Waveforms during subinterval 2 <br> Diode conduction interval

Inductor voltages and capacitor currents:

$$
\begin{aligned}
& v_{L 1}=V_{g}-v_{1} \\
& v_{L 2}=-v_{2} \\
& i_{C 1}=i_{1} \\
& i_{C 2}=i_{2}-\frac{v_{2}}{R}
\end{aligned}
$$



Small ripple approximation for subinterval 2:

$$
\begin{aligned}
& v_{L 1}=V_{g}-V_{1} \\
& v_{L 2}=-V_{2} \\
& i_{C 1}=I_{1} \\
& i_{C 2}=I_{2}-\frac{V_{2}}{R}
\end{aligned}
$$

## Equate average values to zero

The principles of inductor volt-second and capacitor charge balance state that the average values of the periodic inductor voltage and capacitor current waveforms are zero, when the converter operates in steady state. Hence, to determine the steady-state conditions in the converter, let us sketch the inductor voltage and capacitor current waveforms, and equate their average values to zero.

## Waveforms:

Inductor voltage $v_{L 1}(t)$


Volt-second balance on $L_{1}$ :

$$
\left\langle v_{L 1}\right\rangle=D V_{g}+D^{\prime}\left(V_{g}-V_{1}\right)=0
$$

## Equate average values to zero

Inductor $L_{2}$ voltage


Capacitor $C_{1}$ current


Average the waveforms:

$$
\begin{aligned}
& \left\langle v_{L 2}\right\rangle=D\left(-V_{1}-V_{2}\right)+D^{\prime}\left(-V_{2}\right)=0 \\
& \left\langle i_{C 1}\right\rangle=D I_{2}+D^{\prime} I_{1}=0
\end{aligned}
$$

## Equate average values to zero

Capacitor current $i_{C 2}(t)$ waveform
$i_{C 2}(t)$

$$
\stackrel{I_{2}-V_{2} / R(=0)}{\rightleftarrows T_{s} \longrightarrow\left|\longleftarrow D^{\prime} T_{s} \longrightarrow\right|}
$$

$$
\left\langle i_{C 2}\right\rangle=I_{2}-\frac{V_{2}}{R}=0
$$

Note: during both subintervals, the capacitor current $i_{C 2}$ is equal to the difference between the inductor current $i_{2}$ and the load current $V_{2} / R$. When ripple is neglected, $i_{C 2}$ is constant and equal to zero.

## Cuk converter conversion ratio $M=V / V_{g}$



## Inductor current waveforms

Interval 1 slopes, using small ripple approximation:

$$
\begin{aligned}
& \frac{d i_{1}(t)}{d t}=\frac{v_{L 1}(t)}{L_{1}}=\frac{V_{g}}{L_{1}} \\
& \frac{d i_{2}(t)}{d t}=\frac{v_{L 2}(t)}{L_{2}}=\frac{-V_{1}-V_{2}}{L_{2}}
\end{aligned}
$$



Interval 2 slopes:

$$
\begin{aligned}
& \frac{d i_{1}(t)}{d t}=\frac{v_{L 1}(t)}{L_{1}}=\frac{V_{g}-V_{1}}{L_{1}} \\
& \frac{d i_{2}(t)}{d t}=\frac{v_{L 2}(t)}{L_{2}}=\frac{-V_{2}}{L_{2}}
\end{aligned}
$$



## Capacitor $C_{1}$ waveform

Subinterval 1:

$$
\frac{d v_{1}(t)}{d t}=\frac{i_{C 1}(t)}{C_{1}}=\frac{I_{2}}{C_{1}}
$$

Subinterval 2:

$$
\frac{d v_{1}(t)}{d t}=\frac{i_{C 1}(t)}{C_{1}}=\frac{I_{1}}{C_{1}}
$$

## Ripple magnitudes

Analysis results

$$
\begin{aligned}
& \Delta i_{1}=\frac{V_{g} D T_{s}}{2 L_{1}} \\
& \Delta i_{2}=\frac{V_{1}+V_{2}}{2 L_{2}} D T_{s} \\
& \Delta v_{1}=\frac{-I_{2} D T_{s}}{2 C_{1}}
\end{aligned}
$$

Use dc converter solution to simplify:

$$
\begin{aligned}
& \Delta i_{1}=\frac{V_{g} D T_{s}}{2 L_{1}} \\
& \Delta i_{2}=\frac{V_{g} D T_{s}}{2 L_{2}} \\
& \Delta v_{1}=\frac{V_{g} D^{2} T_{s}}{2 D^{\prime} R C_{1}}
\end{aligned}
$$

Q: How large is the output voltage ripple?

### 2.5 Estimating ripple in converters containing two-pole low-pass filters

Buck converter example: Determine output voltage ripple


## Capacitor current and voltage, buck example

Must not neglect inductor current ripple!

If the capacitor voltage ripple is small, then essentially all of the ac component of inductor current flows through the capacitor.


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## Estimating capacitor voltage ripple $\Delta v$



Current $i_{C}(t)$ is positive for half of the switching period. This positive current causes the capacitor voltage $v_{C}(t)$ to increase between its minimum and maximum extrema.
During this time, the total charge $q$ is deposited on the capacitor plates, where

$$
q=C(2 \Delta v)
$$

$($ change in charge $)=$
$C$ (change in voltage)

## Estimating capacitor voltage ripple $\Delta v$



The total charge $q$ is the area of the triangle, as shown:

$$
q=\frac{1}{2} \Delta i_{L} \frac{T_{s}}{2}
$$

Eliminate $q$ and solve for $\Delta v$ :

$$
\Delta v=\frac{\Delta i_{L} T_{s}}{8 C}
$$

Note: in practice, capacitor equivalent series resistance (esr) further increases $\Delta v$.

## Inductor current ripple in two-pole filters



### 2.6 Summary of Key Points

1. The dc component of a converter waveform is given by its average value, or the integral over one switching period, divided by the switching period. Solution of a dc-dc converter to find its dc, or steadystate, voltages and currents therefore involves averaging the waveforms.
2. The linear ripple approximation greatly simplifies the analysis. In a welldesigned converter, the switching ripples in the inductor currents and capacitor voltages are small compared to the respective dc components, and can be neglected.
3. The principle of inductor volt-second balance allows determination of the dc voltage components in any switching converter. In steady-state, the average voltage applied to an inductor must be zero.

## Summary of Chapter 2

4. The principle of capacitor charge balance allows determination of the dc components of the inductor currents in a switching converter. In steadystate, the average current applied to a capacitor must be zero.
5. By knowledge of the slopes of the inductor current and capacitor voltage waveforms, the ac switching ripple magnitudes may be computed. Inductance and capacitance values can then be chosen to obtain desired ripple magnitudes.
6. In converters containing multiple-pole filters, continuous (nonpulsating) voltages and currents are applied to one or more of the inductors or capacitors. Computation of the ac switching ripple in these elements can be done using capacitor charge and/or inductor flux-linkage arguments, without use of the small-ripple approximation.
7. Converters capable of increasing (boost), decreasing (buck), and inverting the voltage polarity (buck-boost and Cuk) have been described. Converter circuits are explored more fully in a later chapter.

## Chapter 3: Steady-State Equivalent Circuit Modeling, Losses, and Efficiency

- 3.1 The dc transformer model
- 3.2 Inclusion of inductor copper loss
- 3.3 Construction of equivalent circuit model
- 3.4 How to obtain the input port of the model
- 3.5 Example: inclusion of semiconductor conduction losses in the boost converter model
- 3.6 Summary of key points


### 3.1. The dc transformer model

Basic equations of an ideal dc-dc converter:

$$
\begin{array}{ll}
P_{\text {in }}=P_{\text {out }} & (\eta=100 \%) \quad \begin{array}{c}
\text { Power } \\
\text { input }
\end{array} \\
V_{g} I_{g}=V I & \\
V=M(D) V_{g} & \text { (ideal conversion ratio) } \\
I_{g}=M(D) I &
\end{array}
$$



Control input

These equations are valid in steady-state. During transients, energy storage within filter elements may cause $P_{\text {in }} \neq P_{\text {out }}$

## Equivalent circuits corresponding to ideal dc-dc converter equations

$$
P_{\text {in }}=P_{\text {out }} \quad V_{g} I_{g}=V I \quad V=M(D) V_{g} \quad I_{g}=M(D) I
$$



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## The DC transformer model



- Solid line denotes ideal transformer model, capable of passing dc voltages and currents
- Time-invariant model (no switching) which can be solved to find dc components of converter waveforms


## Example: use of the DC transformer model


2. Insert dc transformer model

3. Push source through transformer

4. Solve circuit

$$
V=M(D) V_{1} \frac{R}{R+M^{2}(D) R_{1}}
$$

### 3.2. Inclusion of inductor copper loss

Dc transformer model can be extended, to include converter nonidealities.
Example: inductor copper loss (resistance of winding):


Insert this inductor model into boost converter circuit:


## Analysis of nonideal boost converter



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## Circuit equations, switch in position 1

Inductor current and capacitor voltage:

$$
\begin{aligned}
& v_{L}(t)=V_{g}-i(t) R_{L} \\
& i_{C}(t)=-v(t) / R
\end{aligned}
$$



Small ripple approximation:

$$
\begin{aligned}
& v_{L}(t)=V_{g}-I R_{L} \\
& i_{C}(t)=-V / R
\end{aligned}
$$

## Circuit equations, switch in position 2



$$
\begin{aligned}
& v_{L}(t)=V_{g}-i(t) R_{L}-v(t) \approx V_{g}-I R_{L}-V \\
& i_{C}(t)=i(t)-v(t) / R \approx I-V / R
\end{aligned}
$$

## Inductor voltage and capacitor current waveforms

Average inductor voltage:

$$
v_{L}(t)
$$

$$
\begin{aligned}
& \left\langle v_{L}(t)\right\rangle=\frac{1}{T_{s}} \int_{0}^{T_{s}} v_{L}(t) d t \\
& =D\left(V_{g}-I R_{L}\right)+D^{\prime}\left(V_{g}-I R_{L}-V\right)
\end{aligned}
$$



Inductor volt-second balance:

$$
0=V_{g}-I R_{L}-D^{\prime} V
$$

Average capacitor current:

$$
\left\langle i_{c}(t)\right\rangle=D(-V / R)+D^{\prime}(I-V / R)
$$

$i_{C}(t)$


Capacitor charge balance:

$$
0=D^{\prime} I-V / R
$$

## Solution for output voltage

We now have two equations and two unknowns:
$0=V_{g}-I R_{L}-D^{\prime} V$
$0=D^{\prime} I-V / R$
Eliminate $I$ and solve for $V$ :

$$
\frac{V}{V_{g}}=\frac{1}{D^{\prime}} \frac{1}{\left(1+R_{L} / D^{\prime 2} R\right)}
$$



### 3.3. Construction of equivalent circuit model

Results of previous section (derived via inductor volt-sec balance and capacitor charge balance):

$$
\begin{aligned}
& \left\langle v_{L}\right\rangle=0=V_{g}-I R_{L}-D^{\prime} V \\
& \left\langle i_{C}\right\rangle=0=D^{\prime} I-V / R
\end{aligned}
$$

View these as loop and node equations of the equivalent circuit.
Reconstruct an equivalent circuit satisfying these equations

## Inductor voltage equation

$$
\left\langle v_{L}\right\rangle=0=V_{g}-I R_{L}-D^{\prime} V
$$

- Derived via Kirchhoff's voltage law, to find the inductor voltage during each subinterval
- Average inductor voltage then set to zero
- This is a loop equation: the dc components of voltage around a loop containing the inductor sum to zero


## Capacitor current equation

$$
\left\langle i_{c}\right\rangle=0=D^{\prime} I-V / R
$$

- Derived via Kirchoff's current law, to find the capacitor current during each subinterval
- Average capacitor current then set to zero
- This is a node equation: the dc components of current flowing into a node connected to the capacitor sum to zero


## Complete equivalent circuit

The two circuits, drawn together:


The dependent sources are equivalent to a $D^{\prime}: 1$ transformer:


Dependent sources and transformers


- sources have same coefficient
- reciprocal voltage/current dependence


## Solution of equivalent circuit

Converter equivalent circuit


Refer all elements to transformer secondary:


Solution for output voltage using voltage divider formula:

$$
V=\frac{V_{g}}{D^{\prime}} \frac{R}{R+\frac{R_{L}}{D^{\prime 2}}}=\frac{V_{g}}{D^{\prime}} \frac{1}{1+\frac{R_{L}}{D^{\prime 2} R}}
$$

## Solution for input (inductor) current



## Solution for converter efficiency

$$
\begin{aligned}
& P_{\text {in }}=\left(V_{g}\right)(I) \\
& P_{\text {out }}=(V)\left(D^{\prime} I\right) \\
& \eta=\frac{P_{\text {out }}}{P_{\text {in }}}=\frac{(V)\left(D^{\prime} I\right)}{\left(V_{g}\right)(I)}=\frac{V}{V_{g}} D^{\prime} \\
& \eta=\frac{1}{1+\frac{R_{L}}{D^{\prime 2} R}}
\end{aligned}
$$



## Efficiency, for various values of $R_{L}$



### 3.4. How to obtain the input port of the model

Buck converter example -use procedure of previous section to derive equivalent circuit


Average inductor voltage and capacitor current:

$$
\left\langle v_{L}\right\rangle=0=D V_{g}-I_{L} R_{L}-V_{C} \quad\left\langle i_{C}\right\rangle=0=I_{L}-V_{C} / R
$$

## Construct equivalent circuit as usual

$$
\left\langle v_{L}\right\rangle=0=D V_{g}-I_{L} R_{L}-V_{C} \quad\left\langle i_{C}\right\rangle=0=I_{L}-V_{C} R
$$



What happened to the transformer?

- Need another equation


## Modeling the converter input port

Input current waveform $i_{g}(t)$ :


Dc component (average value) of $i_{g}(t)$ is

$$
I_{g}=\frac{1}{T_{s}} \int_{0}^{T_{s}} i_{g}(t) d t=D I_{L}
$$

## Input port equivalent circuit

$$
I_{g}=\frac{1}{T_{s}} \int_{0}^{T_{s}} i_{g}(t) d t=D I_{L}
$$



## Complete equivalent circuit, buck converter

Input and output port equivalent circuits, drawn together:


Replace dependent sources with equivalent dc transformer:


### 3.5. Example: inclusion of semiconductor conduction losses in the boost converter model

Boost converter example


Models of on-state semiconductor devices:
MOSFET: on-resistance $R_{\text {on }}$
Diode: constant forward voltage $V_{D}$ plus on-resistance $R_{D}$
Insert these models into subinterval circuits

## Boost converter example: circuits during subintervals 1 and 2



## Average inductor voltage and capacitor current



## Construction of equivalent circuits

$$
V_{g}-I R_{L}-I D R_{o n}-D^{\prime} V_{D}-I D^{\prime} R_{D}-D^{\prime} V=0
$$


$D^{\prime} I-V / R=0$


## Complete equivalent circuit



## Solution for output voltage



$$
\begin{aligned}
& V=\left(\frac{1}{D^{\prime}}\right)\left(V_{g}-D^{\prime} V_{D}\right)\left(\frac{D^{\prime 2} R}{D^{\prime 2} R+R_{L}+D R_{o n}+D^{\prime} R_{D}}\right) \\
& \frac{V}{V_{g}}=\left(\frac{1}{D^{\prime}}\right)\left(1-\frac{D^{\prime} V_{D}}{V_{g}}\right)\left(\frac{1}{1+\frac{R_{L}+D R_{o n}+D^{\prime} R_{D}}{D^{\prime 2} R}}\right)
\end{aligned}
$$

## Solution for converter efficiency

$$
\begin{aligned}
& P_{\text {in }}=\left(V_{g}\right)(I) \\
& P_{\text {out }}=(V)\left(D^{\prime} I\right)
\end{aligned}
$$



$$
\eta=D^{\prime} \frac{V}{V_{g}}=\frac{\left(1-\frac{D^{\prime} V_{D}}{V_{g}}\right)}{\left(1+\frac{R_{L}+D R_{o n}+D^{\prime} R_{D}}{D^{\prime 2} R}\right)}
$$

Conditions for high efficiency:

$$
\begin{aligned}
V_{g} / D^{\prime} & \gg V_{D} \\
D^{\prime 2} R & \gg R_{L}+D R_{o n}+D^{\prime} R_{D}
\end{aligned}
$$

## Accuracy of the averaged equivalent circuit in prediction of losses

- Model uses average currents and voltages
- To correctly predict power loss in a resistor, use rms values
- Result is the same, provided ripple is small

MOSFET current waveforms, for various ripple magnitudes:


| Inductor current ripple | MOSFET rms current | Average power loss in $R_{\text {on }}$ |
| :--- | :---: | :---: |
| (a) $\Delta i=0$ | $I \sqrt{D}$ | $D I^{2} R_{o n}$ |
| (b) $\Delta i=0.1 I$ | $(1.00167) I \sqrt{D}$ | $(1.0033) D I^{2} R_{\text {on }}$ |
| (c) $\Delta i=I$ | $(1.155) I \sqrt{D}$ | $(1.3333) D I^{2} R_{\text {on }}$ |

## Summary of chapter 3

1. The dc transformer model represents the primary functions of any dc-dc converter: transformation of dc voltage and current levels, ideally with $100 \%$ efficiency, and control of the conversion ratio $M$ via the duty cycle $D$. This model can be easily manipulated and solved using familiar techniques of conventional circuit analysis.
2. The model can be refined to account for loss elements such as inductor winding resistance and semiconductor on-resistances and forward voltage drops. The refined model predicts the voltages, currents, and efficiency of practical nonideal converters.
3. In general, the dc equivalent circuit for a converter can be derived from the inductor volt-second balance and capacitor charge balance equations. Equivalent circuits are constructed whose loop and node equations coincide with the volt-second and charge balance equations. In converters having a pulsating input current, an additional equation is needed to model the converter input port; this equation may be obtained by averaging the converter input current.

## Chapter 13: Basic Magnetics Theory

- Inductor example
- 13.1.2 Magnetic circuits
- 13.2 Transformer modeling
- 13.2.1 The ideal transformer
- 13.2.2 The magnetizing inductance
- 13.2.3 Leakage inductances
- 13.3 Loss mechanisms in magnetic devices
- 13.3.1 Core loss
- 13.3.2 Low-frequency copper loss
- 13.4 Eddy currents in winding conductors
- 13.4.1 Intro to the skin and proximity effects
- Discussion: design of winding geometry to minimize proximity loss
- Litz wire


## Example: a simple inductor

## Faraday's law:

For each turn of wire, we can write

$$
v_{\text {turn }}(t)=\frac{d \Phi(t)}{d t}
$$

Total winding voltage is

$$
v(t)=n v_{\text {turn }}(t)=n \frac{d \Phi(t)}{d t}
$$



Express in terms of the average flux density $B(t)=\mathscr{\mathscr { T }}(t) / A_{c}$

$$
v(t)=n A_{c} \frac{d B(t)}{d t}
$$

## Inductor example: Ampere's law

Choose a closed path which follows the average magnetic field line around the interior of the core. Length of this path is called the mean magnetic path length $\ell_{m}$.

For uniform field strength $H(t)$, the core MMF around the path is $H \ell_{m}$.


Winding contains $n$ turns of wire, each carrying current $i(t)$. The net current passing through the path interior (i.e., through the core window) is $n i(t)$.

From Ampere's law, we have

$$
H(t) \ell_{m}=n i(t)
$$

## Inductor example: core material model

$$
B= \begin{cases}B_{\text {sat }} & \text { for } H \geq B_{\text {sat }} / \mu \\ \mu H & \text { for }|H|<B_{s a t} / \mu \\ -B_{\text {sat }} & \text { for } H \leq-B_{\text {sat }} / \mu\end{cases}
$$



Find winding current at onset of saturation: substitute $i=I_{\text {sat }}$ and $H=B_{\text {sat }} / \mu$ into equation previously derived via Ampere's law. Result is

$$
I_{s a t}=\frac{B_{s a t} \ell_{m}}{\mu n}
$$

## Electrical terminal characteristics

$$
\begin{aligned}
& \text { We have: } \\
& \qquad v(t)=n A_{c} \frac{d B(t)}{d t} \quad H(t) \ell_{m}=n i(t) \quad B= \begin{cases}B_{\text {sat }} & \text { for } H \geq B_{\text {sat }} / \mu \\
\mu H & \text { for }|H|<B_{\text {sat }} / \mu \\
-B_{\text {sat }} & \text { for } H \leq-B_{\text {sat }} / \mu\end{cases}
\end{aligned}
$$

Eliminate $B$ and $H$, and solve for relation between $v$ and $i$. For $|i|<I_{\text {sat }}$,

$$
v(t)=\mu n A_{c} \frac{d H(t)}{d t} \quad \longrightarrow \quad v(t)=\frac{\mu n^{2} A_{c}}{\ell_{m}} \frac{d i(t)}{d t}
$$

which is of the form

$$
v(t)=L \frac{d i(t)}{d t} \quad \text { with } \quad L=\frac{\mu n^{2} A_{c}}{\ell_{m}}
$$

For $|i|>I_{\text {sat }}$ the flux density is constant and equal to $B_{\text {sat }}$. Faraday's law then predicts

$$
v(t)=n A_{c} \frac{d B_{\text {sat }}}{d t}=0 \quad \text {-saturation leads to short circuit }
$$

### 13.1.2 Magnetic circuits

Uniform flux and magnetic field inside a rectangular element:

MMF between ends of element is

$$
\mathscr{T}=H \ell
$$



Since $H=B / \mu$ and $B=\Phi / A_{c}$, we can express $\mathscr{T}$ as

$$
\mathscr{T}=\Phi \mathscr{R} \quad \text { with } \quad \mathscr{R}=\frac{\ell}{\mu A_{c}}
$$

A corresponding model:

$\mathscr{R}=$ reluctance of element

Magnetic circuits: magnetic structures composed of multiple windings and heterogeneous elements

- Represent each element with reluctance
- Windings are sources of MMF
- MMF $\rightarrow$ voltage, flux $\rightarrow$ current
- Solve magnetic circuit using Kirchoff's laws, etc.


## Magnetic analog of Kirchoff's current law

Divergence of $\boldsymbol{B}=0$
Flux lines are continuous and cannot end

Total flux entering a node must be zero


Magnetic circuit


## Magnetic analog of Kirchoff's voltage law

Follows from Ampere's law:


Left-hand side: sum of MMF's across the reluctances around the closed path

Right-hand side: currents in windings are sources of MMF's. An $n$-turn winding carrying current $i(t)$ is modeled as an MMF (voltage) source, of value $n i(t)$.

Total MMF's around the closed path add up to zero.

## Example: inductor with air gap



## Magnetic circuit model

Core


$$
\begin{aligned}
\mathscr{F}_{c}+\mathscr{F}_{g}=n i & \mathscr{R}_{c}=\frac{\ell_{c}}{\mu A_{c}} \\
n i=\Phi\left(\mathscr{R}_{c}+\mathscr{R}_{g}\right) & \mathscr{R}_{g}=\frac{\ell_{g}}{\mu_{0} A_{c}}
\end{aligned}
$$



## Solution of model



Faraday's law: $\quad v(t)=n \frac{d \Phi(t)}{d t}$
Substitute for $\Phi: \quad v(t)=\frac{n^{2}}{\mathscr{R}_{c}+\mathscr{R}_{g}} \frac{d i(t)}{d t}$
Hence inductance is

$$
L=\frac{n^{2}}{\mathscr{R}_{c}+\mathscr{R}_{g}}
$$

## Effect of air gap

$$
\begin{aligned}
& n i=\Phi\left(\mathscr{R}_{c}+\mathscr{R}_{g}\right) \\
& L=\frac{n^{2}}{\mathscr{R}_{c}+\mathscr{R}_{g}} \\
& \Phi_{\text {sat }}=B_{\text {sat }} A_{c} \\
& I_{\text {sat }}=\frac{B_{s a t} A_{c}}{n}\left(\mathscr{R}_{c}+\mathscr{R}_{g}\right)
\end{aligned}
$$

Effect of air gap:

- decrease inductance
- increase saturation current
- inductance is less dependent on core permeability



### 13.2 Transformer modeling

Two windings, no air gap:

$$
\begin{gathered}
\mathscr{R}=\frac{\ell_{m}}{\mu A_{c}} \\
\mathscr{F}_{c}=n_{1} i_{1}+n_{2} i_{2} \\
\Phi \mathscr{R}=n_{1} i_{1}+n_{2} i_{2}
\end{gathered}
$$



Magnetic circuit model:


### 13.2.1 The ideal transformer

In the ideal transformer, the core reluctance $\mathscr{R}$ approaches zero.

MMF $\mathscr{\mathscr { F }}_{c}=\Phi \mathscr{R}$ also approaches zero. We then obtain

$$
0=n_{1} i_{1}+n_{2} i_{2}
$$



Also, by Faraday's law,

$$
\begin{aligned}
& v_{1}=n_{1} \frac{d \Phi}{d t} \\
& v_{2}=n_{2} \frac{d \Phi}{d t}
\end{aligned}
$$

Eliminate $\Phi$ :

$$
\frac{d \Phi}{d t}=\frac{v_{1}}{n_{1}}=\frac{v_{2}}{n_{2}}
$$

Ideal transformer equations:

$$
\frac{v_{1}}{n_{1}}=\frac{v_{2}}{n_{2}} \quad \text { and } \quad n_{1} i_{1}+n_{2} i_{2}=0
$$



Chapter 13: Basic Magnetics Theory

### 13.2.2 The magnetizing inductance

For nonzero core reluctance, we obtain

$$
\Phi \mathscr{R}=n_{1} i_{1}+n_{2} i_{2} \quad \text { with } \quad v_{1}=n_{1} \frac{d \Phi}{d t}
$$

Eliminate $\Phi$ :

$$
v_{1}=\frac{n_{1}^{2}}{\mathscr{R}} \frac{d}{d t}\left[i_{1}+\frac{n_{2}}{n_{1}} i_{2}\right]
$$



This equation is of the form

$$
\begin{aligned}
& \qquad v_{1}=L_{M} \frac{d i_{M}}{d t} \\
& \text { with } \\
& \qquad \begin{array}{l}
L_{M}=\frac{n_{1}^{2}}{\mathscr{R}} \\
i_{M}=i_{1}+\frac{n_{2}}{n_{1}} i_{2}
\end{array}
\end{aligned}
$$



Chapter 13: Basic Magnetics Theory

## Magnetizing inductance: discussion

- Models magnetization of core material
- A real, physical inductor, that exhibits saturation and hysteresis
- If the secondary winding is disconnected:
we are left with the primary winding on the core
primary winding then behaves as an inductor
the resulting inductor is the magnetizing inductance, referred to the primary winding
- Magnetizing current causes the ratio of winding currents to differ from the turns ratio


## Transformer saturation

- Saturation occurs when core flux density $B(t)$ exceeds saturation flux density $B_{\text {sat }}$.
- When core saturates, the magnetizing current becomes large, the impedance of the magnetizing inductance becomes small, and the windings are effectively shorted out.
- Large winding currents $i_{1}(t)$ and $i_{2}(t)$ do not necessarily lead to saturation. If

$$
0=n_{1} i_{1}+n_{2} i_{2}
$$

then the magnetizing current is zero, and there is no net magnetization of the core.

- Saturation is caused by excessive applied volt-seconds


## Saturation vs. applied volt-seconds

Magnetizing current depends on the integral of the applied winding voltage:

$$
i_{M}(t)=\frac{1}{L_{M}} \int v_{1}(t) d t
$$

Flux density is proportional:

$$
B(t)=\frac{1}{n_{1} A_{c}} \int v_{1}(t) d t
$$

### 13.2.3 Leakage inductances



## Transformer model, including leakage inductance

Terminal equations can be written in the form
$\left[\begin{array}{l}v_{1}(t) \\ v_{2}(t)\end{array}\right]=\left[\begin{array}{ll}L_{11} & L_{12} \\ L_{12} & L_{22}\end{array}\right] \frac{d}{d t}\left[\begin{array}{l}i_{1}(t) \\ i_{2}(t)\end{array}\right]$
mutual inductance:


$$
L_{12}=\frac{n_{1} n_{2}}{\mathscr{R}}=\frac{n_{2}}{n_{1}} L_{M}
$$

primary and secondary self-inductances:

$$
\begin{aligned}
& L_{11}=L_{\ell 1}+\frac{n_{1}}{n_{2}} L_{12} \\
& L_{22}=L_{\ell 2}+\frac{n_{2}}{n_{1}} L_{12}
\end{aligned}
$$

$$
\text { effective turns ratio } \quad n_{e}=\sqrt{\frac{L_{22}}{L_{11}}}
$$

$$
\text { coupling coefficient } \quad k=\frac{L_{12}}{\sqrt{L_{11} L_{22}}}
$$

### 13.3 Loss mechanisms in magnetic devices

Low-frequency losses:
Dc copper loss
Core loss: hysteresis loss
High-frequency losses: the skin effect
Core loss: classical eddy current losses
Eddy current losses in ferrite cores
High frequency copper loss: the proximity effect
Proximity effect: high frequency limit
MMF diagrams, losses in a layer, and losses in basic multilayer windings

Effect of PWM waveform harmonics

### 13.3.1 Core loss

Energy per cycle $W$ flowing into $n$ turn winding of an inductor, excited by periodic waveforms of frequency $f$ :

$$
W=\int_{\text {one cycle }} v(t) i(t) d t
$$

Relate winding voltage and current to core $B$
 and $H$ via Faraday's law and Ampere's law:

$$
v(t)=n A_{c} \frac{d B(t)}{d t} \quad H(t) \ell_{m}=n i(t)
$$

Substitute into integral:

$$
\begin{aligned}
W & =\int_{\text {one cycle }}\left(n A_{c} \frac{d B(t)}{d t}\right)\left(\frac{H(t) \ell_{m}}{n}\right) d t \\
& =\left(A_{c} \ell_{m}\right) \int_{\text {one cycle }} H d B
\end{aligned}
$$

## Core loss: Hysteresis loss

$$
W=\left(A_{c} \ell_{m}\right) \int_{\text {one cycle }} H d B
$$

The term $A_{c} \ell_{m}$ is the volume of the core, while the integral is the area of the $B-H$ loop.

$($ energy lost per cycle $)=($ core volume $)($ area of $B-H$ loop $)$

$$
P_{H}=(f)\left(A_{c} \ell_{m}\right) \int_{\text {one cycle }} H d B
$$

Hysteresis loss is directly proportional to applied frequency

## Modeling hysteresis loss

- Hysteresis loss varies directly with applied frequency
- Dependence on maximum flux density: how does area of $B-H$ loop depend on maximum flux density (and on applied waveforms)? Empirical equation (Steinmetz equation):

$$
P_{H}=K_{H} f B_{\max }^{\alpha}(\text { core volume })
$$

The parameters $K_{H}$ and $\alpha$ are determined experimentally.
Dependence of $P_{H}$ on $B_{\text {max }}$ is predicted by the theory of magnetic domains.

## Core loss: eddy current loss

Magnetic core materials are reasonably good conductors of electric current. Hence, according to Lenz's law, magnetic fields within the core induce currents ("eddy currents") to flow within the core. The eddy currents flow such that they tend to generate a flux which opposes changes in the core flux $\Phi(t)$. The eddy currents tend to prevent flux from penetrating the core.


Eddy current loss $i^{2}(t) R$

## Modeling eddy current loss

- Ac flux $\Phi(t)$ induces voltage $v(t)$ in core, according to Faraday's law. Induced voltage is proportional to derivative of $\Phi(t)$. In consequence, magnitude of induced voltage is directly proportional to excitation frequency $f$.
- If core material impedance $Z$ is purely resistive and independent of frequency, $Z=R$, then eddy current magnitude is proportional to voltage: $i(t)=v(t) / R$. Hence magnitude of $i(t)$ is directly proportional to excitation frequency $f$.
- Eddy current power loss $i^{2}(t) R$ then varies with square of excitation frequency $f$.
- Classical Steinmetz equation for eddy current loss:

$$
P_{E}=K_{E} f^{2} B_{\max }^{2}(\text { core volume })
$$

- Ferrite core material impedance is capacitive. This causes eddy current power loss to increase as $f^{4}$.


## Total core loss: manufacturer's data

Ferrite core material


Empirical equation, at a fixed frequency:

$$
P_{f e}=K_{f e}(\Delta B)^{\beta} A_{c} \ell_{m}
$$

## Core materials

| Core type | $B_{\text {sat }}$ | Relative core loss | Applications |
| :---: | :---: | :---: | :---: |
| Laminations iron, silicon steel | 1.5-2.0 T | high | $50-60 \mathrm{~Hz}$ transformers, inductors |
| Powdered cores powdered iron, molypermalloy | 0.6-0.8 T | medium | 1 kHz transformers, 100 kHz filter inductors |
| Ferrite Manganese-zinc, Nickel-zinc | 0.25-0.5 T | low | $20 \mathrm{kHz}-1 \mathrm{MHz}$ transformers, ac inductors |

### 13.3.2 Low-frequency copper loss

DC resistance of wire

$$
R=\rho \frac{\ell_{b}}{A_{w}}
$$

where $A_{w}$ is the wire bare cross-sectional area, and $\ell_{b}$ is the length of the wire. The resistivity $\rho$ is equal to $1.724 \cdot 10^{-6} \Omega \mathrm{~cm}$ for soft-annealed copper at room temperature. This resistivity increases to $2.3 \cdot 10^{-6} \Omega \mathrm{~cm}$ at $100^{\circ} \mathrm{C}$.

The wire resistance leads to a power loss of

$$
P_{c u}=I_{r m s}^{2} R
$$



### 13.4 Eddy currents in winding conductors 13.4.1 Intro to the skin and proximity effects



## Penetration depth $\delta$

For sinusoidal currents: current density is an exponentially decaying function of distance into the conductor, with characteristic length $\delta$ known as the penetration depth or skin depth.

Wire diameter

$$
\delta=\sqrt{ } \frac{\rho}{\pi \mu f}
$$

For copper at room temperature:

$$
\delta=\frac{7.5}{\sqrt{f}} \mathrm{~cm}
$$



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## The proximity effect

Ac current in a conductor induces eddy currents in adjacent conductors by a process called the proximity effect. This causes significant power loss in the windings of high-frequency transformers and ac inductors.

A multi-layer foil winding, with $h \gg \delta$. Each layer carries net current $i(t)$.


## Example: a two-winding transformer

Cross-sectional view of two-winding transformer example. Primary turns are wound in three layers. For this example, let's assume that each layer is one turn of a flat foil conductor. The secondary is a similar three-layer winding. Each layer carries net current $i(t)$. Portions of the windings that lie outside of the core window are not illustrated. Each layer has thickness $h \gg \delta$.

## Distribution of currents on surfaces of conductors: two-winding example

Skin effect causes currents to concentrate on surfaces of conductors

Surface current induces equal and opposite current on adjacent conductor

This induced current returns on opposite side of conductor

Net conductor current is equal to $i(t)$ for each layer, since layers are connected in series

Circulating currents within layers increase with the numbers of layers

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## Estimating proximity loss: high-frequency limit

The current $i(t)$ having rms value $I$ is confined to thickness $d$ on the surface of layer 1 . Hence the effective "ac" resistance of layer 1 is:

$$
R_{a c}=\frac{h}{\delta} R_{d c}
$$

This induces copper loss $P_{1}$ in layer 1 :

$$
P_{1}=I^{2} R_{a c}
$$

Power loss $P_{2}$ in layer 2 is:

$$
P_{2}=P_{1}+4 P_{1}=5 P_{1}
$$

Power loss $P_{3}$ in layer 3 is:

$$
P_{3}=\left(2^{2}+3^{2}\right) P_{1}=13 P_{1}
$$



Power loss $P_{m}$ in layer $m$ is:

$$
\left.P_{m}=I^{2} \mid(m-1)^{2}+m^{2}\right]\left(\frac{h}{\delta} R_{d c}\right)
$$

## Total loss in M-layer winding: high-frequency limit

Add up losses in each layer:

$$
\begin{aligned}
P & =I^{2}\left(\frac{h}{\delta} R_{d c}\right) \sum_{m=1}^{M}\left[(m-1)^{2}+m^{2}\right] \\
& =I^{2}\left(\frac{h}{\delta} R_{d c}\right) \frac{M}{3}\left(2 M^{2}+1\right)
\end{aligned}
$$

Compare with dc copper loss:
If foil thickness were $H=\delta$, then at dc each layer would produce copper loss $P_{1}$. The copper loss of the $M$-layer winding would be

$$
P_{d c}=I^{2} M R_{d c}
$$

So the proximity effect increases the copper loss by a factor of

$$
F_{R}=\frac{P}{P_{d c}}=\frac{1}{3}\left(\frac{h}{\delta}\right)\left(2 M^{2}+1\right)
$$

## Discussion: design of winding geometry to minimize proximity loss

- Interleaving windings can significantly reduce the proximity loss when the winding currents are in phase, such as in the transformers of buckderived converters or other converters
- In some converters (such as flyback or SEPIC) the winding currents are out of phase. Interleaving then does little to reduce the peak MMF and proximity loss. See Vandelac and Ziogas [10].
- For sinusoidal winding currents, there is an optimal conductor thickness near $\varphi=1$ that minimizes copper loss.
- Minimize the number of layers. Use a core geometry that maximizes the width $\ell_{w}$ of windings.
- Minimize the amount of copper in vicinity of high MMF portions of the windings


## Litz wire

- A way to increase conductor area while maintaining low proximity losses
- Many strands of small-gauge wire are bundled together and are externally connected in parallel
- Strands are twisted, or transposed, so that each strand passes equally through each position on inside and outside of bundle. This prevents circulation of currents between strands.
- Strand diameter should be sufficiently smaller than skin depth
- The Litz wire bundle itself is composed of multiple layers
- Advantage: when properly sized, can significantly reduce proximity loss
- Disadvantage: increased cost and decreased amount of copper within core window


## Practical realisations and simulations

- Transformer ( 50 Hz )
- Transformer ( 20 kHz )
- Inductors
- Simulations with ONELAB


## Chapter 4: Switch Realization

- Diode
- Physics of the diode: charge-controlled behavior
- Switching losses
- Ringing induced by diode stored charge
- Examples of diodes
- MOSFET
- Physics of the MOSFET
- Static characteristics
- Output capacitance
- Hard switching losses
- Examples of MOSFET
- Other power semi-conductors


## Forward-biased power diode



## Charge-controlled behavior of the diode

The diode equation:

$$
q(t)=Q_{0}\left(e^{\lambda v(t)}-1\right)
$$

Charge control equation:

$$
\frac{d q(t)}{d t}=i(t)-\frac{q(t)}{\tau_{L}}
$$

With:
$\lambda=1 /(26 \mathrm{mV})$ at 300 K
$\tau_{L}=$ minority carrier lifetime
(above equations don't
include current that
charges depletion region capacitance)
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In equilibrium: $d q / d t=0$, and hence

$$
i(t)=\frac{q(t)}{\tau_{L}}=\frac{Q_{0}}{\tau_{L}}\left(e^{\lambda v(t)}-1\right)=I_{0}\left(e^{\lambda v(t)}-1\right)
$$

## Charge-control in the diode: Discussion

- The familiar $i-v$ curve of the diode is an equilibrium relationship that can be violated during transient conditions
- During the turn-on and turn-off switching transients, the current deviates substantially from the equilibrium $i-v$ curve, because of change in the stored charge and change in the charge within the reverse-bias depletion region
- Under forward-biased conditions, the stored minority charge causes "conductivity modulation" of the resistance of the lightly-doped $n^{-}$region, reducing the device on-resistance


## Diode in OFF state: reversed-biased, blocking voltage



- Diode is reverse-biased
- No stored minority charge: $q=0$
- Depletion region blocks applied reverse voltage; charge is stored in capacitance of depletion region



## Turn-on transient



The current $i(t)$ is determined by the converter circuit. This current supplies:

- charge to increase voltage across depletion region
- charge needed to support the on-state current
- charge to reduce on-resistance of $n^{-}$ region


## Turn-off transient



## Diode turn-off transient continued



## The diode switching transients induce switching loss in the transistor



- Diode recovered stored charge $Q_{r}$ flows through transistor during transistor turn-on transition, inducing switching loss
- $Q_{r}$ depends on diode on-state forward current, and on the rate-of-change of diode current during diode turn-off transition

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## Diode reverse recovery: transistor induced losses

## Excerpt of [1]:

Losses are induced in the transistor because the diode reverse voltage takes time to establish.
Assuming abrupt recovery, losses are essentially present in the transistor:

$$
\begin{aligned}
W_{T} & =\int_{t_{0} \rightarrow t_{1}} v_{A}(t) i_{A}(t) d t \\
& \approx \int_{t_{0} \rightarrow t_{1}} V_{g}\left(i_{L}-i_{B}(t)\right) d t \\
& =V_{g} i_{L}\left(t_{1}-t_{0}\right)+V_{g} Q_{r} .
\end{aligned}
$$



Soft-recovery diode:
$\left(t_{2}-t_{1}\right) \gg\left(t_{1}-t_{0}\right)$
Abrupt-recovery diode:
$\left(t_{2}-t_{l}\right) \ll\left(t_{l}-t_{0}\right)$

## Diode reverse recovery: diode losses

Once the transistor is closed, the diode sees the full voltage and experiences a non negligible trailing current (soft recovery case):

$$
\begin{aligned}
W_{D} & =\int_{t_{1} \rightarrow t_{2}} v_{B}(t) i_{B}(t) d t \\
& \approx \int_{t_{1} \rightarrow t_{2}}-V_{g} \cdot i_{B}(t) d t \\
& =-V_{g} \int_{t_{1} \rightarrow t_{2}} i_{B}(t) d t \\
& =V_{g} Q_{\text {red }}
\end{aligned}
$$

Modified figure of [1]:


## Ringing induced by diode stored charge



- Diode is forward-biased while $i_{L}(t)>0$
- Negative inductor current removes diode stored charge $Q_{r}$
- When diode becomes reverse-biased, negative inductor current flows through capacitor $C$.
- Ringing of $L-C$ network is damped by parasitic losses. Ringing energy is lost.



## Energy associated with ringing

Recovered charge is

$$
Q_{r}=-\int_{t_{2}}^{t_{3}} i_{L}(t) d t
$$

Energy stored in inductor during interval $t_{2} \leq t \leq t_{3}$ :

$$
W_{L}=\int_{t_{2}}^{t_{3}} v_{L}(t) i_{L}(t) d t
$$

Applied inductor voltage during interval $t_{2} \leq t \leq t_{3}$ :

$$
v_{L}(t)=L \frac{d i_{L}(t)}{d t}=-V_{2}
$$

Hence,

$$
\begin{aligned}
& W_{L}=\int_{t_{2}}^{t_{3}} L \frac{d i_{L}(t)}{d t} i_{L}(t) d t=\int_{t_{2}}^{t_{3}}\left(-V_{2}\right) i_{L}(t) d t \\
& W_{L}=\frac{1}{2} L i_{L}^{2}\left(t_{3}\right)=V_{2} Q_{r}
\end{aligned}
$$



## Diode: static characteristic example

## Excerpt of IXYS DSEP29-12A diode data-sheet:



Fig. 1 Forward current $\mathrm{I}_{\mathrm{F}}$ vs. $\mathrm{V}_{\mathrm{F}}$

## Diode: recovery characteristics example

## Excerpt of IXYS DSEP29-12A diode data-sheet:



Fig. 2 Typ. reverse recovery charge $Q_{r}$ versus -dif $/ \mathrm{dt}$


Fig. 3 Typ. peak reverse current $\mathrm{I}_{\mathrm{RM}}$ versus $-\mathrm{di}_{\mathrm{F}} / \mathrm{dt}$

## Types of power diodes

## Standard recovery

Reverse recovery time not specified, intended for $50 / 60 \mathrm{~Hz}$
Fast recovery and ultra-fast recovery
Reverse recovery time and recovered charge specified Intended for converter applications

## Schottky diode

A majority carrier device
Essentially no recovered charge
Model with equilibrium $i-v$ characteristic, in parallel with depletion region capacitance
Restricted to low voltage (few devices can block 100 V or more)

## Characteristics of several commercial power rectifier diodes

| Part number | Rated max voltage | Rated avg current | $V_{F}$ (typical) | $t_{r}(\max )$ |
| :---: | :---: | :---: | :---: | :---: |
| Fast recovery rectifiers |  |  |  |  |
| 1N3913 | 400 V | 30A | 1.1 V | 400 ns |
| SD453N25S20PC | 2500 V | 400A | 2.2 V | $2 \mu \mathrm{~s}$ |
| Ultra-fast recovery rectifiers |  |  |  |  |
| MUR815 | 150 V | 8A | 0.975 V | 35 ns |
| MUR 1560 | 600 V | 15A | 1.2 V | 60 ns |
| RHRU100120 | 1200 V | 100A | 2.6 V | 60 ns |
| Schottky rectifiers |  |  |  |  |
| MBR6030L | 30 V | 60A | 0.48 V |  |
| 444 CNQ 045 | 45 V | 440A | 0.69 V |  |
| $30 \mathrm{CPQ150}$ | 150 V | 30A | 1.19 V |  |

### 4.2.2. The Power MOSFET



- Gate lengths approaching one micron
- Consists of many small enhancementmode parallelconnected MOSFET cells, covering the surface of the silicon wafer
- Vertical current flow
- n-channel device is shown


## MOSFET: Off state



- $p-n$ - junction is reverse-biased
- off-state voltage appears across $\mathrm{n}^{-}$ region



## MOSFET: on state



Fundamentals of Power Electronics

- $p-n$ - junction is slightly reversebiased
- positive gate voltage induces conducting channel
- drain current flows through $n$ region and conducting channel
- on resistance $=$ total resistances of $n$ region, conducting channel, source and drain contacts, etc.


## MOSFET body diode



- $p-n$ - junction forms an effective diode, in parallel with the channel
- negative drain-tosource voltage can forward-bias the body diode
- diode can conduct the full MOSFET rated current
- diode switching speed not optimized -body diode is slow, $Q_{r}$ is large


## Typical MOSFET characteristics



- Off state: $V_{G S}<V_{t h}$
- On state: $V_{G S} \gg V_{t h}$
- MOSFET can conduct peak currents well in excess of average current rating -characteristics are unchanged
- on-resistance has positive temperature coefficient, hence easy to parallel


## A simple MOSFET equivalent circuit



- $C_{g s}$ : large, essentially constant
- $C_{g d}$ : small, highly nonlinear
- $C_{d s}$ : intermediate in value, highly nonlinear
- switching times determined by rate at which gate driver charges/discharges $C_{g s}$ and $C_{g d}$
$C_{d s}\left(v_{d s}\right) \approx C_{0} \sqrt{\frac{V_{0}}{v_{d s}}}=\frac{C_{0}}{\sqrt{v_{d s}}}$


## Switching loss caused by semiconductor output capacitances

## Buck converter example



Energy lost during MOSFET turn-on transition
(assuming linear capacitances):

$$
W_{C}=\frac{1}{2}\left(C_{d s}+C_{j}\right) V_{g}^{2}
$$

## MOSFET nonlinear $C_{d s}$

Incremental $C_{d s}\left(v_{d s}\right)$ is approximated by: $C_{d s}\left(v_{d s}\right) \approx \frac{C_{0}^{\prime}}{\sqrt{V_{d s}}}$. The energy stored in $C_{d s}$ at $v_{d s}=V_{D S}$ :

$$
\begin{aligned}
W_{C_{d s}} & =\int v_{d s} i_{C} d t=\int v_{d s} C_{d s}\left(v_{d s}\right) \frac{d v_{d s}(t)}{d t} d t=\int_{0}^{V_{D s}} v_{d s} C_{d s}\left(v_{d s}\right) d v_{d s} \\
& =\int_{0}^{V_{D S}} \frac{C_{0}^{\prime}}{\sqrt{v_{d s}}} v_{d s} d v_{d s}=\int_{0}^{V_{D s}} C_{0}^{\prime} \sqrt{v_{d s}} d v_{d s} \\
& =\frac{2}{3} C_{0}^{\prime} V_{d s}^{\frac{3}{2}}=\frac{2}{3} \frac{C_{0}^{\prime}}{\sqrt{V_{d s}}} V_{d s}^{2}=\frac{1}{2} \frac{4}{3} C_{d s}\left(V_{d s}\right) V_{d s}^{2} .
\end{aligned}
$$

The energy loss is equivalent to the energy loss related to a voltage independant capacitor but taking $\frac{4}{3}$ of the capacitance value at $V_{d s}$.

## MOSFET: hard switching losses circuit example

- Boost converter considered.
- The reasoning also applied to other circuits in hard switching.
- Diode D is considered ideal is this case.



## MOSFET: hard switching losses waveforms




Power losses $=$ area $E_{\text {on }}$ and $E_{\text {off }}$ (energy) times $f_{s}$ (switching frequency):

$$
P_{\text {ON }}=\frac{1}{2} V \cdot l \cdot\left(t_{3}-t_{1}\right) \cdot f_{s} \quad \quad \text { POFF }=\frac{1}{2} V \cdot l \cdot\left(t_{3}-t_{1}\right) \cdot f_{s}
$$

## MOSFET: hard switching losses explanations

Turn-On (left figure on previous slide):
$t_{0} \rightarrow t_{1}$ : the gate voltage $v_{G S}(t)$ rises from 0 to $V_{t h}$.
$t_{1} \rightarrow t_{2}$ : the drain current $i_{D S}(t)$ rises according to $v_{G S}(t)$ change (linked by the transconductance). Once $i_{D S}(t)$ reaches $I$, the transistor carries the full load current.
$t_{2} \rightarrow t_{3}: v_{G S}(t)$ stays at the "plateau" voltage $V_{p l}$ due to the Miller effect and the drain voltage $v_{D S}(t)$ falls linearly.
$t_{3} \rightarrow t_{4}$ : once $v_{D S}(t)$ reaches $0 V$ at $t_{3}, v_{G S}(t)$ continues to rise up to $V_{d r}$.

Turn-Off (right figure on previous slide):
$t_{0} \rightarrow t_{1}: V_{G S}(t)$ falls from $V_{d r}$ to $V_{p l}$.
$t_{1} \rightarrow t_{2}$ : when $v_{G S}(t)$ reaches $V_{p l}, v_{D S}(t)$ starts rising linearly. $v_{G S}(t)$ stays at $V_{p /}$ due to the Miller effect.
$t_{2} \rightarrow t_{3}$ : once $v_{D S}(t)$ reaches $V, v_{G S}(t)$ starts falling again and $i_{D S}(t)$ also starts falling accordingly (linked by the transconductance).
$t_{3} \rightarrow t_{4}$ : once $v_{G S}(t)$ reaches $V_{t h}, i_{D S}(t)$ reaches $0 V$ and $v_{G S}(t)$ goes to 0 V .

## MOSFET: static characteristics example

Excerpt of IR IRFP4668PbF MOSFET data-sheet:



## MOSFET: dynamic characteristics example

## Excerpt of IR IRFP4668PbF MOSFET data-sheet:




## Characteristics of several commercial power MOSFETs

| Part number | Rated max voltage | Rated avg current | $R_{\text {on }}$ | $Q_{g}$ (typical) |
| :---: | :---: | :---: | :---: | :---: |
| IRFZ48 | 60 V | 50 A | $0.018 \Omega$ | 110 nC |
| IRF510 | 100 V | 5.6 A | $0.54 \Omega$ | 8.3 nC |
| IRF540 | 100 V | 28 A | $0.077 \Omega$ | 72 nC |
| APT10M25BNR | 100 V | 75 A | $0.025 \Omega$ | 171 nC |
| IRF740 | 400 V | 10 A | $0.55 \Omega$ | 63 nC |
| MTM15N40E | 400 V | 15 A | $0.3 \Omega$ | 110 nC |
| APT5025BN | 500 V | 23 A | $0.25 \Omega$ | 83 nC |
| APT1001RBNR | 1000 V | 11 A | $1.0 \Omega$ | 150 nC |

## MOSFET: conclusions

- A majority-carrier device: fast switching speed
- Typical switching frequencies: tens and hundreds of kHz
- On-resistance increases rapidly with rated blocking voltage
- Easy to drive
- The device of choice for blocking voltages less than 500 V
- 1000 V devices are available, but are useful only at low power levels (100W)
- Part number is selected on the basis of on-resistance rather than current rating


## Other power semi-conductors (brief overview)

Thyristor: high voltage, high current, switches off at zero current,
GTO (gate turn off Thyristor): similar to Thyristor but can be switched off with the gate signal,
IGBT (Isolated Gate Bipolar Transistor): high voltage, high current, controlled like a MOSFET,

BJT transistor: not often used, replaced by MOSFET,
Schottky diode: diode with higher conduction and switching performances but lower breakdown voltage,
SiC diode: emerging component that could/will replace diodes,
SiC transistor: emerging component that could/will replace IGBT,
GaN transistor: emerging component that could/will replace MOSFET.

## Other power semi-conductors

## Excerpt of [4]:



ELEC0055: Elements of Power Electronics - Fall 2020

## Chapter 5: The Discontinuous Conduction Mode

- Introduction to Discontinuous Conduction Mode (DCM)
- 5.1 Origin of the discontinuous conduction mode, and mode boundary
- 5.2 Analysis of the conversion ratio $M(D, K)$
- 5.3 Boost converter example
- Summary of results and key points


## Introduction to Discontinuous Conduction Mode (DCM)

- Occurs because switching ripple in inductor current or capacitor voltage causes polarity of applied switch current or voltage to reverse, such that the current- or voltage-unidirectional assumptions made in realizing the switch are violated.
- Commonly occurs in dc-dc converters and rectifiers, having singlequadrant switches. May also occur in converters having two-quadrant switches.
- Typical example: dc-dc converter operating at light load (small load current). Sometimes, dc-dc converters and rectifiers are purposely designed to operate in DCM at all loads.
- Properties of converters change radically when DCM is entered:
$M$ becomes load-dependent
Output impedance is increased
Dynamics are altered
Control of output voltage may be lost when load is removed


### 5.1. Origin of the discontinuous conduction mode, and mode boundary

Buck converter example, with single-quadrant switches


Minimum diode current is $\left(I-\Delta i_{L}\right)$ Dc component $I=V / R$ Current ripple is

$$
\Delta i_{L}=\frac{\left(V_{g}-V\right)}{2 L} D T_{s}=\frac{V_{g} D D^{\prime} T_{s}}{2 L}
$$

Note that $I$ depends on load, but $\Delta i_{L}$ does not.
continuous conduction mode (CCM)



[^0]
## Reduction of load current

Increase $R$, until $I=\Delta i_{L}$


Minimum diode current is $\left(I-\Delta i_{L}\right)$
Dc component $I=V / R$ Current ripple is

$$
\Delta i_{L}=\frac{\left(V_{g}-V\right)}{2 L} D T_{s}=\frac{V_{g} D D^{\prime} T_{s}}{2 L}
$$

Note that $I$ depends on load, but $\Delta i_{L}$ does not.

## Further reduce load current

Increase $R$ some more, such that $I<\Delta i_{L}$


Minimum diode current is $\left(I-\Delta i_{L}\right)$
Dc component $I=V / R$
Current ripple is

$$
\Delta i_{L}=\frac{\left(V_{g}-V\right)}{2 L} D T_{s}=\frac{V_{g} D D^{\prime} T_{s}}{2 L}
$$

Note that $I$ depends on load, but $\Delta i_{L}$ does not.
The load current continues to be positive and non-zero.

Discontinuous conduction mode


Chapter 5: Discontinuous conduction mode

## Mode boundary

$$
\begin{array}{ll}
I>\Delta i_{L} & \text { for } C C M \\
I<\Delta i_{L} & \text { for } D C M
\end{array}
$$

Insert buck converter expressions for $I$ and $\Delta i_{L}$ :

$$
\frac{D V_{g}}{R}<\frac{D D^{\prime} T_{s} V_{g}}{2 L}
$$

Simplify:

$$
\frac{2 L}{R T_{s}}<D^{\prime}
$$

This expression is of the form

$$
\begin{array}{lll} 
& K<K_{\text {crit }}(D) \quad \text { for } D C M \\
\text { where } & K=\frac{2 L}{R T_{s}} \quad \text { and } \quad K_{\text {crit }}(D)=D^{\prime}
\end{array}
$$

## $K$ and $K_{\text {crit }}$ vs. $D$

$$
\text { for } K<1 \text { : }
$$


for $K>1$ :


## Critical load resistance $R_{\text {crit }}$

Solve $K_{\text {crit }}$ equation for load resistance $R$ :

$$
\begin{array}{ll} 
& R<R_{\text {crit }}(D) \quad \text { for } C C M \\
& R>R_{\text {crit }}(D) \quad \text { for } D C M \\
\text { where } \quad & R_{\text {crit }}(D)=\frac{2 L}{D^{\prime} T_{s}}
\end{array}
$$

## Summary: mode boundary

$$
\begin{array}{llll}
K>K_{\text {criv }}(D) & \text { or } & R<R_{\text {crit }}(D) & \text { for } C C M \\
K<K_{\text {crit }}(D) & \text { or } & R>R_{\text {crit }}(D) & \text { for } D C M
\end{array}
$$

Table 5.1. CCM-DCM mode boundaries for the buck, boost, and buck-boost converters

| Converter | $K_{\text {crit }}(D)$ | $\max _{0 \leq D \leq 1}\left(K_{\text {crit }}\right)$ | $R_{\text {crit }}(D)$ | $\min _{0 \leq D \leq 1}\left(R_{\text {crit }}\right)$ |
| :--- | :---: | :---: | :---: | :---: |
| Buck | $(1-D)$ | 1 | $\frac{2 L}{(1-D) T_{s}}$ | $2 \frac{L}{T_{s}}$ |
| Boost | $D(1-D)^{2}$ | $\frac{4}{27}$ | $\frac{2 L}{D(1-D)^{2} T_{s}}$ | $\frac{27}{2} \frac{L}{T_{s}}$ |
| Buck-boost | $(1-D)^{2}$ | 1 | $\frac{2 L}{(1-D)^{2} T_{s}}$ | $2 \frac{L}{T_{s}}$ |

### 5.2. Analysis of the conversion ratio $M(D, K)$

Analysis techniques for the discontinuous conduction mode:
Inductor volt-second balance

$$
\left\langle v_{L}\right\rangle=\frac{1}{T_{s}} \int_{0}^{T_{s}} v_{L}(t) d t=0
$$

Capacitor charge balance

$$
\left\langle i_{C}\right\rangle=\frac{1}{T_{s}} \int_{0}^{T_{s}} i_{C}(t) d t=0
$$

Small ripple approximation sometimes applies:

$$
\begin{aligned}
& v(t) \approx V \text { because } \Delta v \ll V \\
& i(t) \approx I \text { is a poor approximation when } \Delta i>I
\end{aligned}
$$

Converter steady-state equations obtained via charge balance on each capacitor and volt-second balance on each inductor. Use care in applying small ripple approximation.

## Example: Analysis of DCM buck converter $M(D, K)$



## Subinterval 1

$$
\begin{aligned}
& v_{L}(t)=V_{g}-v(t) \\
& i_{C}(t)=i_{L}(t)-v(t) / R
\end{aligned}
$$

Small ripple approximation for $v(t)$ (but not for $i(t)!$ ):


$$
\begin{aligned}
& v_{L}(t) \approx V_{g}-V \\
& i_{C}(t) \approx i_{L}(t)-V / R
\end{aligned}
$$

## Subinterval 2

$$
\begin{aligned}
& v_{L}(t)=-v(t) \\
& i_{C}(t)=i_{L}(t)-v(t) / R
\end{aligned}
$$

Small ripple approximation for $v(t)$ but not for $i(t)$ :


$$
\begin{aligned}
& v_{L}(t) \approx-V \\
& i_{C}(t) \approx i_{L}(t)-V / R
\end{aligned}
$$

## Subinterval 3

$$
\begin{aligned}
& v_{L}=0, \quad i_{L}=0 \\
& i_{C}(t)=i_{L}(t)-v(t) / R
\end{aligned}
$$

Small ripple approximation:


$$
\begin{aligned}
& v_{L}(t)=0 \\
& i_{C}(t)=-V / R
\end{aligned}
$$

## Inductor volt-second balance



Volt-second balance:

$$
\left\langle v_{L}(t)\right\rangle=D_{1}\left(V_{g}-V\right)+D_{2}(-V)+D_{3}(0)=0
$$

Solve for $V$ :

$$
V=V_{g} \frac{D_{1}}{D_{1}+D_{2}} \quad \text { note that } D_{2} \text { is unknown }
$$

## Capacitor charge balance

node equation:

$$
i_{L}(t)=i_{C}(t)+V / R
$$

capacitor charge balance:

$$
\left\langle i_{c}\right\rangle=0
$$

hence

$$
\left\langle i_{L}\right\rangle=V / R
$$

must compute dc component of inductor current and equate to load current (for this buck converter example)

## Inductor current waveform

## peak current:

$$
i_{L}\left(D_{1} T_{s}\right)=i_{p k}=\frac{V_{g}-V}{L} D_{1} T_{s}
$$

average current:

$$
\left\langle i_{L}\right\rangle=\frac{1}{T_{s}} \int_{0}^{T_{s}} i_{L}(t) d t
$$


triangle area formula:

$$
\begin{aligned}
& \int_{0}^{T_{s}} i_{L}(t) d t=\frac{1}{2} i_{p k}\left(D_{1}+D_{2}\right) T_{s} \\
& \left\langle i_{L}\right\rangle=\left(V_{g}-V\right) \frac{D_{1} T_{s}}{2 L}\left(D_{1}+D_{2}\right)
\end{aligned}
$$

equate dc component to dc load current:

$$
\frac{V}{R}=\frac{D_{1} T_{s}}{2 L}\left(D_{1}+D_{2}\right)\left(V_{g}-V\right)
$$

## Solution for $V$

Two equations and two unknowns ( $V$ and $D_{2}$ ):

$$
\begin{array}{ll}
V=V_{g} \frac{D_{1}}{D_{1}+D_{2}} & \text { (from inductor volt-second baland } \\
\frac{V}{R}=\frac{D_{1} T_{s}}{2 L}\left(D_{1}+D_{2}\right)\left(V_{g}-V\right) & \text { (from capacitor charge balance) }
\end{array}
$$

Eliminate $D_{2}$, solve for $V$ :

$$
\begin{aligned}
& \qquad \frac{V}{V_{g}}=\frac{2}{1+\sqrt{1+4 K / D_{1}^{2}}} \\
& \text { where } \quad K=2 L / R T_{s} \\
& \text { valid for } \quad K<K_{c r i t}
\end{aligned}
$$

## Buck converter $M(D, K)$



### 5.3. Boost converter example



Mode boundary:

$$
\begin{array}{lll}
I>\Delta i_{L} \text { for } C C M & I=\frac{V_{g}}{D^{\prime 2} R} & \Delta i_{L}=\frac{V_{g}}{2 L} D T_{s} \\
I<\Delta i_{L} \text { for } D C M
\end{array}
$$

## Mode boundary

$$
\begin{array}{ll}
\frac{V_{g}}{D^{\prime 2} R}>\frac{D T_{s} V_{g}}{2 L} \quad \text { for } C C M \\
\frac{2 L}{R T_{s}}>D D^{\prime 2} & \text { for } C C M
\end{array}
$$

$$
\begin{array}{ll} 
& K>K_{c r i t}(D) \quad \text { for } C C M \\
& K<K_{c r i t}(D) \quad \text { for } D C M \\
\text { where } & K=\frac{2 L}{R T_{s}} \quad \text { and } \quad K_{c r i t}(D)=D D^{\prime 2}
\end{array}
$$



## Mode boundary



## Conversion ratio: DCM boost



## Subinterval 1

$$
\begin{aligned}
& v_{L}(t)=V_{g} \\
& i_{C}(t)=-v(t) / R
\end{aligned}
$$

Small ripple approximation for $v(t)$ (but not for $i(t)!$ ):


$$
\begin{aligned}
& v_{L}(t) \approx V_{g} \\
& i_{C}(t) \approx-V / R
\end{aligned}
$$

$$
0<t<D_{1} T_{s}
$$

## Subinterval 2

$$
\begin{aligned}
& v_{L}(t)=V_{g}-v(t) \\
& i_{C}(t)=i(t)-v(t) / R
\end{aligned}
$$

Small ripple approximation for $v(t)$ but not for $i(t)$ :


$$
\begin{aligned}
& v_{L}(t) \approx V_{g}-V \\
& i_{C}(t) \approx i(t)-V / R
\end{aligned}
$$

$$
D_{l} T_{s}<t<\left(D_{l}+D_{2}\right) T_{s}
$$

## Subinterval 3

$$
\begin{aligned}
& v_{L}=0, \quad i=0 \\
& i_{C}(t)=-v(t) / R
\end{aligned}
$$

Small ripple approximation:


$$
\begin{aligned}
& v_{L}(t)=0 \\
& i_{C}(t)=-V / R
\end{aligned}
$$

$$
\left(D_{1}+D_{2}\right) T_{s}<t<T_{s}
$$

## Inductor volt-second balance



Volt-second balance:

$$
D_{1} V_{g}+D_{2}\left(V_{g}-V\right)+D_{3}(0)=0
$$

Solve for $V$ :

$$
V=\frac{D_{1}+D_{2}}{D_{2}} V_{g}
$$

note that $D_{2}$ is unknown

## Capacitor charge balance

node equation:

$$
i_{D}(t)=i_{C}(t)+v(t) / R
$$

capacitor charge balance:

$$
\left\langle i_{c}\right\rangle=0
$$

hence

$$
\left\langle i_{D}\right\rangle=V / R
$$

must compute dc component of diode current and equate to load current
(for this boost converter example)

## Inductor and diode current waveforms

## peak current:

$$
i_{p k}=\frac{V_{g}}{L} D_{1} T_{s}
$$

average diode current:

$$
\left\langle i_{D}\right\rangle=\frac{1}{T_{s}} \int_{0}^{T_{s}} i_{D}(t) d t
$$

triangle area formula:

$$
\int_{0}^{T_{s}} i_{D}(t) d t=\frac{1}{2} i_{p k} D_{2} T_{s}
$$



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## Equate diode current to load current

average diode current:

$$
\left\langle i_{D}\right\rangle=\frac{1}{T_{s}}\left(\frac{1}{2} i_{p k} D_{2} T_{s}\right)=\frac{V_{g} D_{1} D_{2} T_{s}}{2 L}
$$

equate to dc load current:

$$
\frac{V_{g} D_{1} D_{2} T_{s}}{2 L}=\frac{V}{R}
$$

## Solution for $V$

Two equations and two unknowns ( $V$ and $D_{2}$ ):

$$
\begin{array}{ll}
V=\frac{D_{1}+D_{2}}{D_{2}} V_{g} & \text { (from inductor volt-second balance) } \\
\frac{V_{g} D_{1} D_{2} T_{s}}{2 L}=\frac{V}{R} & \text { (from capacitor charge balance) }
\end{array}
$$

Eliminate $D_{2}$, solve for $V$. From volt-sec balance eqn:

$$
D_{2}=D_{1} \frac{V_{g}}{V-V_{g}}
$$

Substitute into charge balance eqn, rearrange terms:

$$
V^{2}-V V_{g}-\frac{V_{g}^{2} D_{1}^{2}}{K}=0
$$

## Solution for $V$

$$
V^{2}-V V_{g}-\frac{V_{g}^{2} D_{1}^{2}}{K}=0
$$

Use quadratic formula:

$$
\frac{V}{V_{g}}=\frac{1 \pm \sqrt{1+4 D_{1}^{2} / K}}{2}
$$

Note that one root leads to positive $V$, while other leads to negative $V$. Select positive root:

$$
\begin{aligned}
& \frac{V}{V_{g}}=M\left(D_{1}, K\right)=\frac{1+\sqrt{1+4 D_{1}^{2} / K}}{2} \\
& \text { where } \quad \begin{array}{ll}
\text { walid for } & K=2 L / R T_{s} \\
\text { v< } K_{\text {crit }}(D)
\end{array}
\end{aligned}
$$

Transistor duty cycle $D=$ interval 1 duty cycle $D_{l}$

## Boost converter characteristics



## Summary of DCM characteristics

Table 5.2. Summary of CCM-DCM characteristics for the buck, boost, and buck-boost converters

| Converter | $K_{\text {crit }}(D)$ | $D C M M(D, K)$ | $D C M D_{2}(D, K)$ | $C C M M(D)$ |
| :--- | :---: | :---: | :---: | :---: |
| Buck | $(l-D)$ | $\frac{2}{1+\sqrt{1+4 K / D^{2}}}$ | $\frac{K}{D} M(D, K)$ | $D$ |
| Boost | $D(l-D)^{2}$ | $\frac{1+\sqrt{1+4 D^{2} / K}}{2}$ | $\frac{K}{D} M(D, K)$ | $\frac{1}{1-D}$ |
| Buck-boost | $(l-D)^{2}$ | $-\frac{D}{\sqrt{K}}$ | $\sqrt{K}$ | $-\frac{D}{1-D}$ |
| with |  |  |  |  |
|  | $K=2 L / R T_{s}$. | $D C M$ occurs for $K<K_{\text {crit }}$. |  |  |

## Summary of DCM characteristics



- DCM buck and boost characteristics are asymptotic to $M=1$ and to the DCM buck-boost characteristic
- DCM buck-boost characteristic is linear
- CCM and DCM characteristics intersect at mode boundary. Actual $M$ follows characteristic having larger magnitude
- DCM boost characteristic is nearly linear


## Summary of key points

1. The discontinuous conduction mode occurs in converters containing current- or voltage-unidirectional switches, when the inductor current or capacitor voltage ripple is large enough to cause the switch current or voltage to reverse polarity.
2. Conditions for operation in the discontinuous conduction mode can be found by determining when the inductor current or capacitor voltage ripples and dc components cause the switch on-state current or off-state voltage to reverse polarity.
3. The dc conversion ratio $M$ of converters operating in the discontinuous conduction mode can be found by application of the principles of inductor volt-second and capacitor charge balance.

## Summary of key points

4. Extra care is required when applying the small-ripple approximation. Some waveforms, such as the output voltage, should have small ripple which can be neglected. Other waveforms, such as one or more inductor currents, may have large ripple that cannot be ignored.
5. The characteristics of a converter changes significantly when the converter enters DCM. The output voltage becomes loaddependent, resulting in an increase in the converter output impedance.

## Chapter 19: Resonant Converters

- Introduction
- 19.1 Sinusoidal analysis of resonant converters
- 19.1.1 Controlled switch network model
- 19.1.2 Modeling the rectifier and capacitive filter networks
- 19.1.3 Resonant tank network
- 19.1.4 Solution of converter voltage conversion ratio $M=\frac{V}{V_{g}}$
- 19.4 Soft switching
19.4.1 Operation of the full bridge below resonance: Zero-current switching
- 19.4.2 Operation of the full bridge above resonance:

Zero-voltage switching

- 19.4.3 The zero-voltage transition converter
- 19.5 Load-dependent properties of resonant converters


## Introduction to Resonant Conversion

Resonant power converters contain resonant L-C networks whose voltage and current waveforms vary sinusoidally during one or more subintervals of each switching period. These sinusoidal variations are large in magnitude, and the small ripple approximation does not apply.

Some types of resonant converters:

- Dc-to-high-frequency-ac inverters
- Resonant dc-dc converters
- Resonant inverters or rectifiers producing line-frequency ac


## A basic class of resonant inverters

Basic circuit


Several resonant tank networks


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3


Chapter 19: Resonant Conversion

## Tank network responds only to fundamental component of switched waveforms





Tank current and output voltage are essentially sinusoids at the switching frequency $f_{s}$.

Output can be controlled by variation of switching frequency, closer to or away from the tank resonant frequency

## Derivation of a resonant dc-dc converter

Rectify and filter the output of a dc-high-frequency-ac inverter


The series resonant dc-dc converter

## A series resonant link inverter

Same as dc-dc series resonant converter, except output rectifiers are replaced with four-quadrant switches:


## Quasi-resonant converters

In a conventional PWM converter, replace the PWM switch network with a switch network containing resonant elements.

Buck converter example


Two
switch networks:


## Resonant conversion: advantages

The chief advantage of resonant converters: reduced switching loss
Zero-current switching
Zero-voltage switching
Turn-on or turn-off transitions of semiconductor devices can occur at zero crossings of tank voltage or current waveforms, thereby reducing or eliminating some of the switching loss mechanisms. Hence resonant converters can operate at higher switching frequencies than comparable PWM converters
Zero-voltage switching also reduces converter-generated EMI
Zero-current switching can be used to commutate SCRs
In specialized applications, resonant networks may be unavoidable
High voltage converters: significant transformer leakage inductance and winding capacitance leads to resonant network

## Resonant conversion: disadvantages

Can optimize performance at one operating point, but not with wide range of input voltage and load power variations

Significant currents may circulate through the tank elements, even when the load is disconnected, leading to poor efficiency at light load
Quasi-sinusoidal waveforms exhibit higher peak values than equivalent rectangular waveforms

These considerations lead to increased conduction losses, which can offset the reduction in switching loss

Resonant converters are usually controlled by variation of switching frequency. In some schemes, the range of switching frequencies can be very large
Complexity of analysis

## Resonant conversion: Outline of discussion

- Simple steady-state analysis via sinusoidal approximation
- Simple and exact results for the series and parallel resonant converters
- Mechanisms of soft switching
- Circulating currents, and the dependence (or lack thereof) of conduction loss on load power
- Quasi-resonant converter topologies
- Steady-state analysis of quasi-resonant converters
- Ac modeling of quasi-resonant converters via averaged switch modeling


### 19.1 Sinusoidal analysis of resonant converters



If tank responds primarily to fundamental component of switch network output voltage waveform, then harmonics can be neglected.

Let us model all ac waveforms by their fundamental components.

## The sinusoidal approximation



Tank current and output voltage are essentially sinusoids at the switching frequency $f_{s}$.
Neglect harmonics of switch output voltage waveform, and model only the fundamental component.
Remaining ac waveforms can be found via phasor analysis.

### 19.1.1 Controlled switch network model



If the switch network produces a square wave, then its output voltage has the following Fourier series:

$$
v_{s}(t)=\frac{4 V_{g}}{\pi} \sum_{n=1,3,5, \ldots} \frac{1}{n} \sin \left(n \omega_{s} t\right)
$$



The fundamental component is

$$
v_{s 1}(t)=\frac{4 V_{g}}{\pi} \sin \left(\omega_{s} t\right)=V_{s 1} \sin \left(\omega_{s} t\right)
$$

So model switch network output port with voltage source of value $v_{s 1}(t)$

## Model of switch network input port



Assume that switch network output current is

$$
i_{s}(t) \approx I_{s 1} \sin \left(\omega_{s} t-\varphi_{s}\right)
$$

It is desired to model the dc component (average value) of the switch network input current.

$$
\begin{aligned}
\left\langle i_{g}(t)\right\rangle_{T_{s}} & =\frac{2}{T_{s}} \int_{0}^{T_{s} / 2} i_{g}(\tau) d \tau \\
& \approx \frac{2}{T_{s}} \int_{0}^{T_{s} / 2} I_{s 1} \sin \left(\omega_{s} \tau-\varphi_{s}\right) d \tau \\
& =\frac{2}{\pi} I_{s 1} \cos \left(\varphi_{s}\right)
\end{aligned}
$$

## Switch network: equivalent circuit



- Switch network converts dc to ac
- Dc components of input port waveforms are modeled
- Fundamental ac components of output port waveforms are modeled
- Model is power conservative: predicted average input and output powers are equal


### 19.1.2 Modeling the rectifier and capacitive filter networks




Assume large output filter capacitor, having small ripple.
$v_{R}(t)$ is a square wave, having zero crossings in phase with tank output current $i_{R}(t)$.

## Sinusoidal approximation: rectifier

Again, since tank responds only to fundamental components of applied waveforms, harmonics in $v_{R}(t)$ can be neglected. $v_{R}(t)$ becomes

$$
v_{R 1}(t)=\frac{4 V}{\pi} \sin \left(\omega_{s} t-\varphi_{R}\right)=V_{R 1} \sin \left(\omega_{s} t-\varphi_{R}\right)
$$

## Actual waveforms


with harmonics ignored


## Rectifier dc output port model



Output capacitor charge balance: dc load current is equal to average rectified tank output current

$$
\langle | i_{R}(t)| \rangle_{T_{s}}=I
$$

Hence

$$
\begin{aligned}
I & =\frac{2}{T_{S}} \int_{0}^{T_{s} / 2} I_{R 1}\left|\sin \left(\omega_{s} t-\varphi_{R}\right)\right| d t \\
& =\frac{2}{\pi} I_{R 1}
\end{aligned}
$$

## Equivalent circuit of rectifier

Rectifier input port:
Fundamental components of current and voltage are sinusoids that are in phase

Hence rectifier presents a resistive load to tank network

Effective resistance $R_{e}$ is

$$
R_{e}=\frac{v_{R 1}(t)}{i_{R}(t)}=\frac{8}{\pi^{2}} \frac{V}{I}
$$



With a resistive load $R$, this becomes

$$
R_{e}=\frac{8}{\pi^{2}} R=0.8106 R
$$

### 19.1.3 Resonant tank network



Model of ac waveforms is now reduced to a linear circuit. Tank network is excited by effective sinusoidal voltage (switch network output port), and is load by effective resistive load (rectifier input port).
Can solve for transfer function via conventional linear circuit analysis.

## Solution of tank network waveforms

Transfer function:

$$
\frac{v_{R 1}(s)}{v_{s 1}(s)}=H(s)
$$

Ratio of peak values of input and output voltages:

$$
\frac{V_{R 1}}{V_{s 1}}=\|H(s)\|_{s=j \omega_{s}}
$$

Solution for tank output current:

$$
i_{R}(s)=\frac{v_{R 1}(s)}{R_{e}}=\frac{H(s)}{R_{e}} v_{s 1}(s)
$$

which has peak magnitude

$$
I_{R 1}=\frac{\|H(s)\|_{s=j \omega_{s}}}{R_{e}} V_{s 1}
$$

### 19.1.4 Solution of converter voltage conversion ratio $M=V / V_{g}$



$$
\begin{aligned}
M=\frac{V}{V_{g}}= & \underbrace{(R)} \underbrace{\left(\frac{2}{\pi}\right)} \underbrace{\left(\frac{1}{R_{e}}\right)}_{\left(\frac{V_{R 1}}{V_{e}}\right)} \underbrace{\left(\|H(s)\|_{s=j \omega_{s}}\right)}_{\left(\frac{V}{I_{R 1}}\right)\left(\frac{V_{s 1}}{V_{R 1}}\right)} \underbrace{\left(\frac{4}{\pi}\right)} \quad \begin{array}{l}
\text { Eliminate } R_{e}: \\
\frac{V}{V_{g}}=\|H(s)\|_{s=j \omega_{s}}
\end{array}
\end{aligned}
$$

## Conversion ratio $M$

$$
\frac{V}{V_{g}}=\|H(s)\|_{s=j \omega_{s}}
$$

So we have shown that the conversion ratio of a resonant converter, having switch and rectifier networks as in previous slides, is equal to the magnitude of the tank network transfer function. This transfer function is evaluated with the tank loaded by the effective rectifier input resistance $R_{e}$.

### 19.4 Soft switching

Soft switching can mitigate some of the mechanisms of switching loss and possibly reduce the generation of EMI
Semiconductor devices are switched on or off at the zero crossing of their voltage or current waveforms:

Zero-current switching: transistor turn-off transition occurs at zero current. Zero-current switching eliminates the switching loss caused by IGBT current tailing and by stray inductances. It can also be used to commutate SCR's.
Zero-voltage switching: transistor turn-on transition occurs at zero voltage. Diodes may also operate with zero-voltage switching. Zero-voltage switching eliminates the switching loss induced by diode stored charge and device output capacitances.
Zero-voltage switching is usually preferred in modern converters.
Zero-voltage transition converters are modified PWM converters, in which an inductor charges and discharges the device capacitances. Zero-voltage switching is then obtained.

### 19.4.1 Operation of the full bridge below resonance: Zero-current switching

Series resonant converter example


Operation below resonance: input tank current leads voltage
Zero-current switching (ZCS) occurs

## Tank input impedance

> Operation below resonance: tank input impedance $Z_{i}$ is dominated by tank capacitor.
> $\angle Z_{i}$ is positive, and tank input current leads tank input voltage.

> Zero crossing of the tank input current waveform $i_{s}(t)$ occurs before the zero crossing of the voltage $v_{s}(t)$.


## Switch network waveforms, below resonance

## Zero-current switching



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Conduction sequence: $Q_{1}-D_{1}-Q_{2}-D_{2}$
$Q_{1}$ is turned off during $D_{1}$ conduction interval, without loss

## ZCS turn-on transition: hard switching



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$Q_{1}$ turns on while $D_{2}$ is conducting. Stored charge of $D_{2}$ and of semiconductor output capacitances must be removed. Transistor turn-on transition is identical to hardswitched PWM, and switching loss occurs.

### 19.4.2 Operation of the full bridge below resonance: Zero-voltage switching

Series resonant converter example


Operation above resonance: input tank current lags voltage
Zero-voltage switching (ZVS) occurs

## Tank input impedance

## Operation above

 resonance: tank input impedance $Z_{i}$ is dominated by tank inductor.$\angle Z_{i}$ is negative, and tank input current lags tank input voltage.

Zero crossing of the tank input current waveform $i_{s}(t)$ occurs
 after the zero crossing of the voltage $v_{s}(t)$.

## Switch network waveforms, above resonance

Zero-voltage switching


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Conduction sequence: $D_{1}-Q_{1}-D_{2}-Q_{2}$
$Q_{1}$ is turned on during $D_{1}$ conduction interval, without loss

## ZVS turn-off transition: hard switching?



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## Soft switching at the ZVS turn-off transition



- Introduce small capacitors $C_{\text {leg }}$ across each device (or use device output capacitances).
- Introduce delay between turn-off of $Q_{1}$ and turn-on of $Q_{2}$.


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Tank current $i_{s}(t)$ charges and discharges $C_{\text {leg }}$. Turn-off transition becomes lossless. During commutation interval, no devices conduct.

So zero-voltage switching exhibits low switching loss: losses due to diode stored charge and device output capacitances are eliminated.

### 19.4.3 The zero-voltage transition converter

Basic version based on full-bridge PWM buck converter


- Can obtain ZVS of all primaryside MOSFETs and diodes
- Secondary-side diodes switch at zero-current, with loss
- Phase-shift control



### 19.5 Load-dependent properties of resonant converters

## Resonant inverter design objectives:

1. Operate with a specified load characteristic and range of operating points

- With a nonlinear load, must properly match inverter output characteristic to load characteristic

2. Obtain zero-voltage switching or zero-current switching

- Preferably, obtain these properties at all loads
- Could allow ZVS property to be lost at light load, if necessary

3. Minimize transistor currents and conduction losses

- To obtain good efficiency at light load, the transistor current should scale proportionally to load current (in resonant converters, it often doesn't!)


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[^0]:    Chapter 5: Discontinuous conduction mode

